

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)TYP}$ | I_D |
|---------------|-----------------|-------|
| 60V | 80mΩ@10V | 3A |
| | 90mΩ@4.5V | |

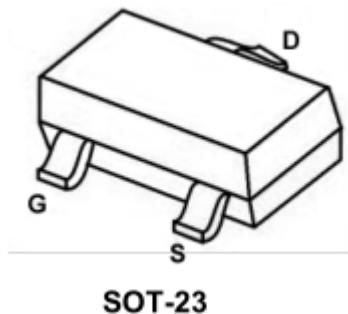
Feature

- High power and current handing capability
- Surface mount package

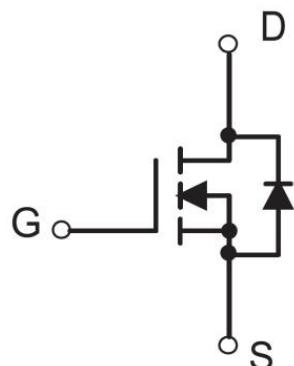
Applications

- Battery switch
- DC/DC converter

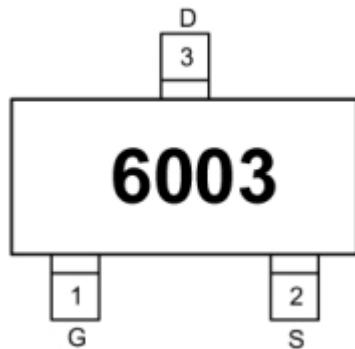
Package



Circuit diagram



Marking



Absolute maximum ratings

($T_a=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|-----------------------------------------------------------|-----------------|----------|---------------------------|
| Drain-Source Voltage | V_{DS} | 60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current | I_D | 3 | A |
| Pulsed Drain Current | I_{DM} | 12 | A |
| Maximum Power Dissipation | P_D | 1.5 | W |
| Thermal Resistance from Junction to Ambient ²⁾ | $R_{\theta JA}$ | 85 | $^\circ\text{C}/\text{W}$ |
| Junction Temperature | T_J | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{STG} | -55~+150 | $^\circ\text{C}$ |

Electrical characteristics

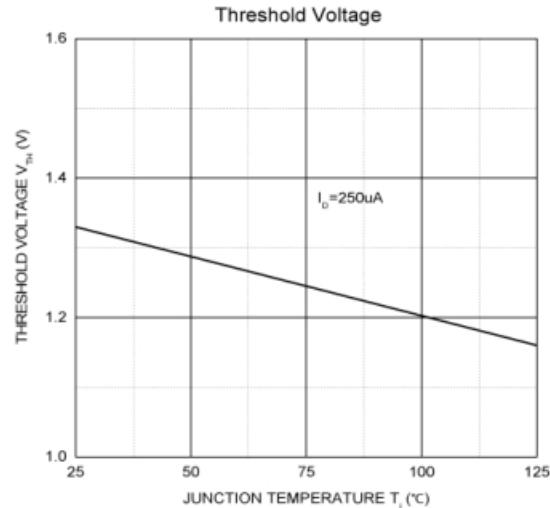
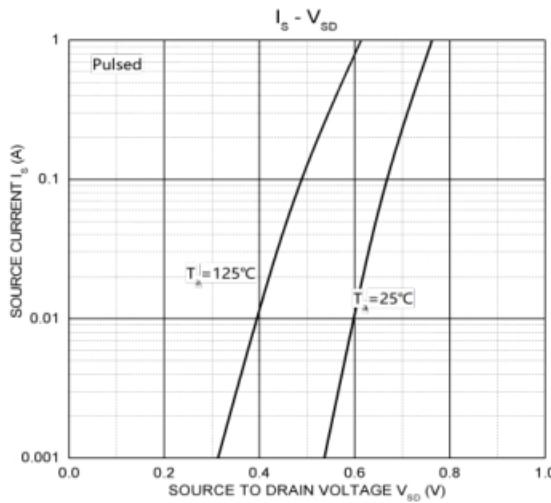
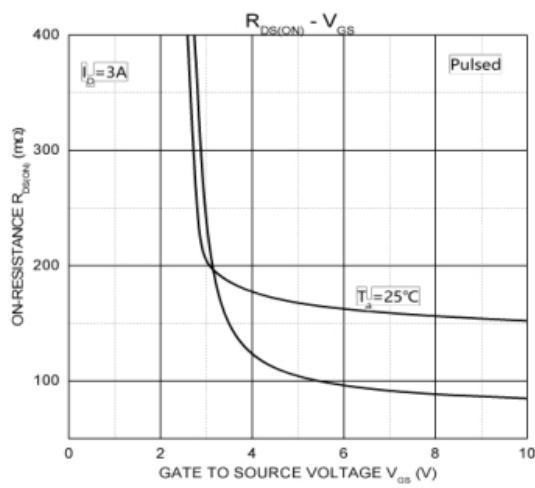
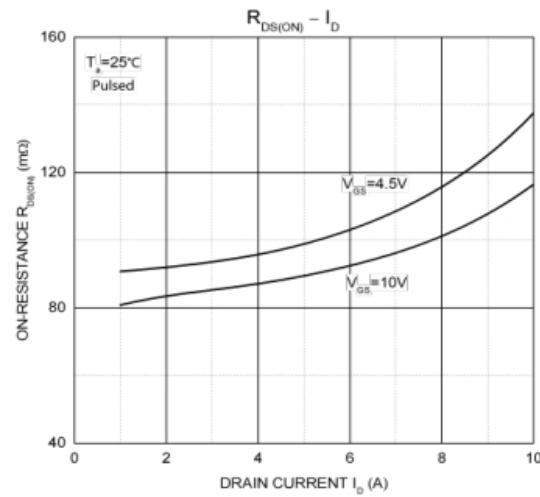
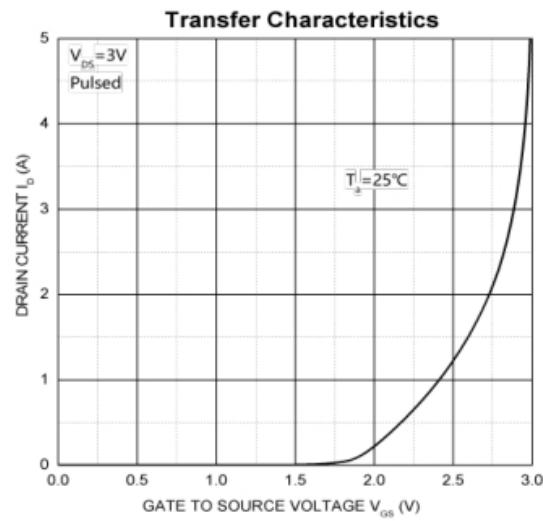
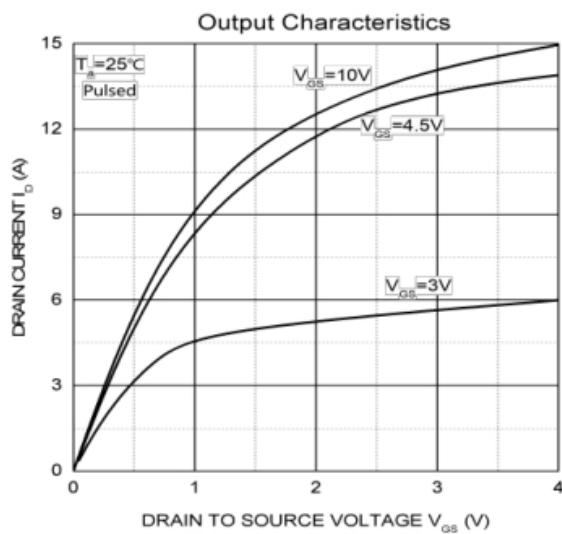
($T_A=25^\circ\text{C}$, unless otherwise noted)

| Parameter | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|-----------------------------------------------|-------------------------------------|--------------------------------------------------------------------------------------------------|------|------|-----------|------------------|
| Static Characteristics | | | | | | |
| Drain-source breakdown voltage | $\text{BV}_{(\text{BR})\text{DSS}}$ | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$ | 60 | | | V |
| Zero gate voltage drain current | I_{DSS} | $V_{DS} = 60\text{V}, V_{GS} = 0\text{V}$ | | | 1 | μA |
| Gate-body leakage current | I_{GSS} | $V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$ | | | ± 100 | μA |
| Gate threshold voltage ⁽¹⁾ | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 0.9 | 1.3 | 2.0 | V |
| Drain-source on-resistance | $R_{DS(\text{on})}$ | $V_{GS} = 10\text{V}, I_D = 3\text{A}$ | | 80 | 100 | $\text{m}\Omega$ |
| | | $V_{GS} = 4.5\text{V}, I_D = 2\text{A}$ | | 90 | 120 | |
| Dynamic Characteristics⁴⁾ | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = 30\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$ | | 330 | | pF |
| Output Capacitance | C_{oss} | | | 90 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 17 | | |
| Total Gate Charge | Q_g | $V_{DS} = 30\text{V}, V_{GS} = 4.5\text{V}, I_D = 3\text{A}$ | | 5.1 | | nC |
| Gate-Source Charge | Q_{gs} | | | 1.3 | | |
| Gate-Drain Charge | Q_{gd} | | | 1.7 | | |
| Switching Characteristics⁴⁾ | | | | | | |
| Turn-on Delay Time | $T_{d(on)}$ | $V_{GS} = 10\text{V}, V_{DD} = 30\text{V}, I_D = 1.5\text{A}, R_L = 1\Omega, R_{GEN} = 3\Omega,$ | | 13 | | nS |
| Turn-on Rise Time | T_r | | | 51 | | |
| Turn-Off Delay Time | $T_{d(off)}$ | | | 19 | | |
| Turn-Off Fall Time | t_f | | | 12 | | |
| Source-Drain Diode Characteristics | | | | | | |
| Body diode voltage | V_{SD} | $I_S = 1\text{A}, V_{GS} = 0\text{V}$ | | | 1.2 | V |

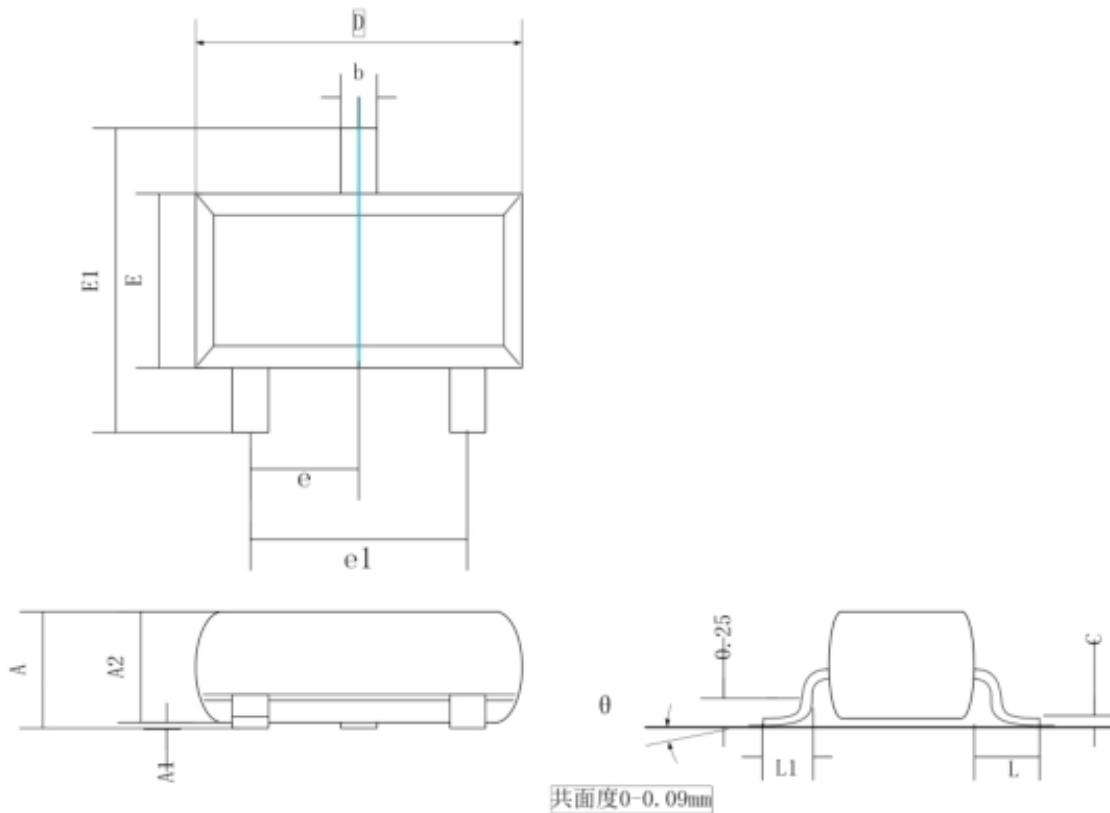
Notes:

1. Repetitive rating: Pulse width limited by junction temperature.
2. Surface mounted on FR4 board, $t \leq 10\text{s}$.
3. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 0.5\%$.
4. Guaranteed by design, not subject to production.

Typical Characteristics



SOT-23 Package Information



| Symbol | Dimensions In Millimeters | |
|--------|---------------------------|------|
| | Min. | Max. |
| A | 0.90 | 1.15 |
| A1 | 0.00 | 0.10 |
| A2 | 0.90 | 1.05 |
| b | 0.30 | 0.50 |
| c | 0.08 | 0.15 |
| D | 2.80 | 3.00 |
| E | 1.20 | 1.40 |
| E1 | 2.25 | 2.55 |
| e | 0.95 REF. | |
| e1 | 1.80 | 2.00 |
| L | 0.55 REF. | |
| L1 | 0.30 | 0.50 |
| θ | 0° | 8° |